

# isc N-Channel MOSFET Transistor

IRF3805, IIRF3805

### • FEATURES

- Static drain-source on-resistance: R<sub>D</sub>s(on) ≤3.3mΩ
- Enhancement mode
- · Fast Switching Speed
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### DESCRITION

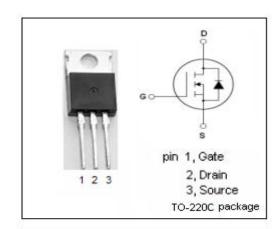
• reliable device for use in a wide variety of applications

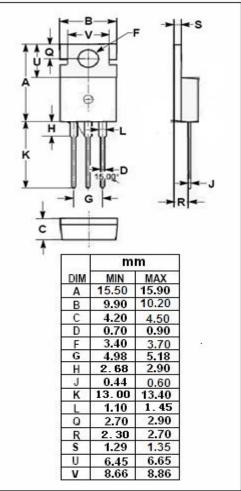
### • ABSOLUTE MAXIMUM RATINGS(T<sub>a</sub>=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	55	V
V <sub>GS</sub>	Gate-Source Voltage	±20	V
I <sub>D</sub>	Drain Current-Continuous	75	А
I <sub>DM</sub>	Drain Current-Single Pulsed	890	А
P <sub>D</sub>	Total Dissipation @T <sub>c</sub> =25℃	300	W
Tj	Max. Operating Junction Temperature	175	${\mathbb C}$
T <sub>stg</sub>	Storage Temperature	-55~175	°C

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	0.5	°C/W
Rth(ch-a)	h(ch-a) Channel-to-ambient thermal resistance		°C/W







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#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 250 μ A	55			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; ID = 250 μ A	2		4	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =75A			3.3	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> =±20V			±0.2	μ <b>А</b>
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =55V; V <sub>GS</sub> = 0V			20	μ <b>A</b>
V <sub>SD</sub>	Diode forward voltage	Is =75A, V <sub>GS</sub> = 0 V			1.3	V

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